

LL24BT1006

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28W Surface Mount TVS Bi-Directional For ESD Protection - 24V

Features

- Small body outline dimensions.
- Protects one I/O or power line.
- Low leakage current.
- Low capacitance : 0.5pF (Typical).
- Provide transient protection:
IEC 61000-4-2 (ESD) $\pm 15\text{KV(Air)}$, $\pm 15\text{KV(Contact)}$.
IEC 61000-4-4 (EFT) 40A (5/50ns).
IEC 61000-4-5 (Lightning) 4A (8/20 μs).
- We declare that the material of product compliance with RoHS requirements.
- Suffix "-H" indicates Halogen-free parts, ex.LL24BT1006-H

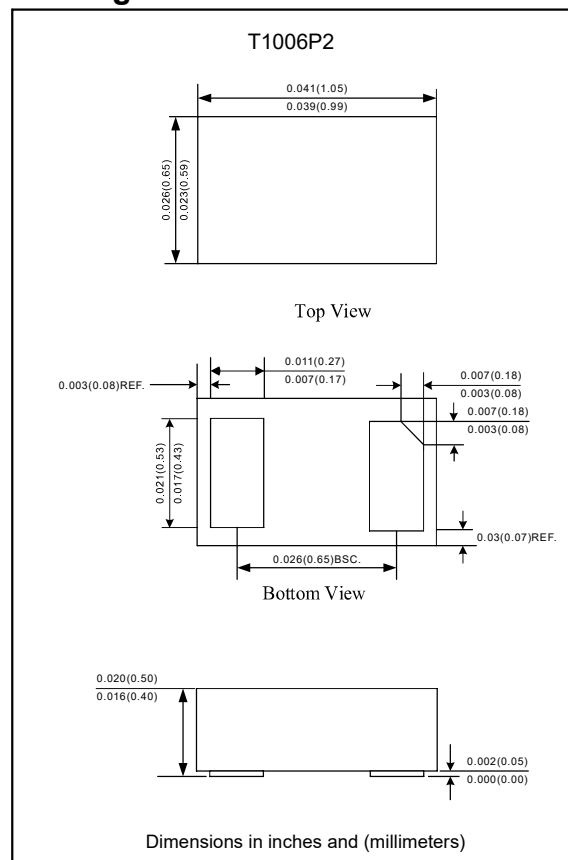
Applications

- Cellular Handsets & Accessories.
- Personal digital assistants (PDAs).
- Notebooks & Handholds.
- Portable instrumentation.
- Digital cameras.

Mechanical data

- T1006P2 package
- Molding compound flammability rating : UL94V-0
- Packaging : Tape and reel per EIA 481
- RoHS Compliant
- Weight : Approximated 0.73 mg

Package outline



Maximum ratings (at $T_A = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Peak pulse power ($t_p = 8/20\mu\text{s}$)	P_{PP}	28	W
Peak pulse current ($t_p = 8/20\mu\text{s}$)	I_{PP}	4	A
ESD per IEC 61000-4-2 (Contact)	V_{ESD}	± 15	KV
ESD per IEC 61000-4-2 (Air)		± 15	
Operating temperature	T_{OPT}	+125	$^\circ\text{C}$
Storage temperature	T_{STG}	-55 to +150	$^\circ\text{C}$

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Electrical characteristics (at $T_J=25^\circ\text{C}$ unless otherwise noted)

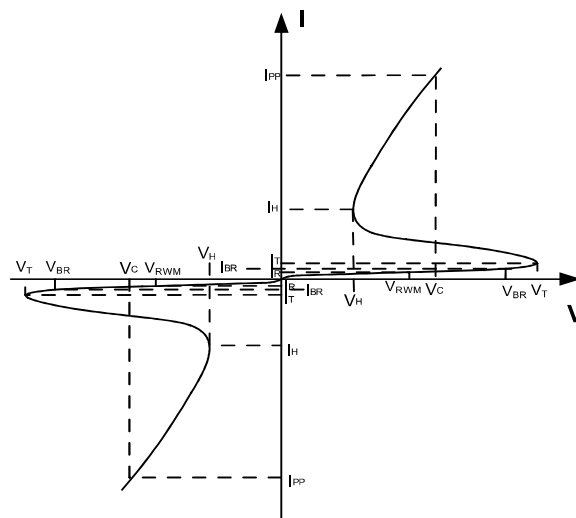
Parameter	Conditions	Symbol	Min.	Typ.	Max.	Unit
Reverse stand-off voltage		V_{RWM}			24	V
Reverse breakdown voltage	$I_T=1\text{mA}$	V_{BR}	27			V
Reverse leakage current	$V_{RWM}=24\text{V}$	I_R			500	nA
Holding current		I_H		50		mA
Clamping voltage	$I_{PP}=4\text{A}$, $t_p=8/20\mu\text{s}$	V_C		5	7	V
ESD Clamping voltage (Note 1)	$I_{PP}=4\text{A}$, $t_p=0.2/100\text{ns}$ (TLP)	V_C		4.4		V
ESD Clamping voltage (Note 1)	$I_{PP}=16\text{A}$, $t_p=0.2/100\text{ns}$ (TLP)	V_C		7.9		V
Dynamic resistance (Note 1, 2)	TLP=0.2/100ns	R_{DYN}		0.29		Ω
Junction capacitance	$V_R=0\text{V}$, $f=1\text{MHz}$	C_J		0.5	0.7	pF

Note : 1. TLP Setting : $t_p=100\text{ns}$, $t_r=0.2\text{ns}$, I_{TLP} and V_{TLP} sample window : $t_1=70\text{ns}$ to $t_2=90\text{ns}$.

2. Dynamic resistance calculated from $I_{PP}=4\text{A}$ to $I_{PP}=16\text{A}$ using "Best fit".

Electrical parameters

Symbol	Parameter
I_{PP}	Reverse Peak Pulse Current
V_C	Clamping Voltage
V_{RWM}	Reverse Stand-Off Voltage
I_{BR}	Reverse Breakdown Current
I_R	Reverse Leakage Current
V_{BR}	Reverse Breakdown Voltage
V_T	Reverse Trigger Voltage
I_T	Reverse Trigger Current
V_H	Reverse Holding Voltage
I_H	Reverse Holding current



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Rating and characteristic curves

Figure 1: Peak Pulse Power vs. Pulse Time

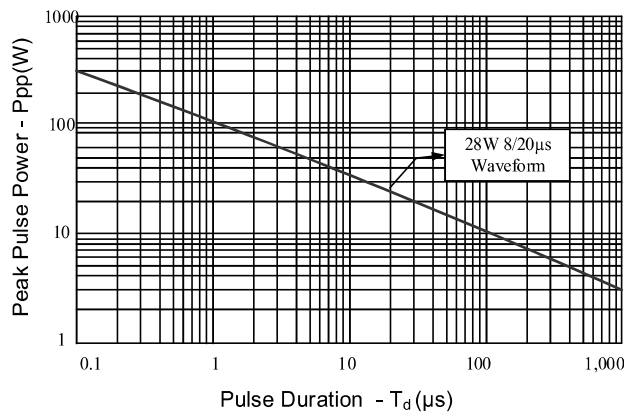


Figure 2: Power Derating Curve

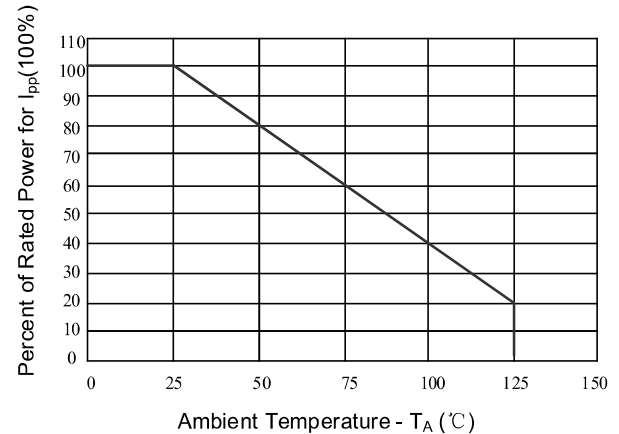


Figure 3: Clamping Voltage vs. Peak Pulse Current

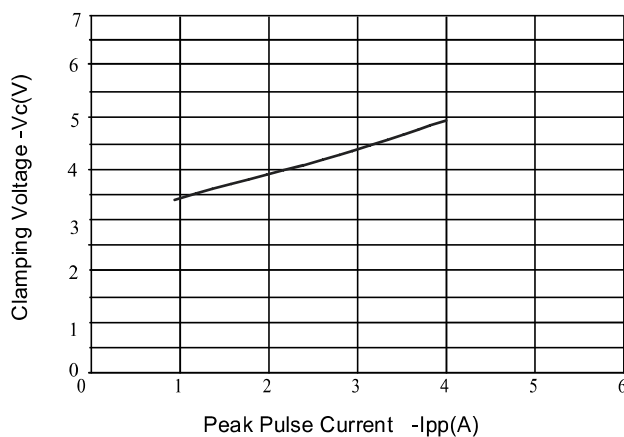


Figure 4: Normalized Junction Capacitance vs. Reverse Voltage

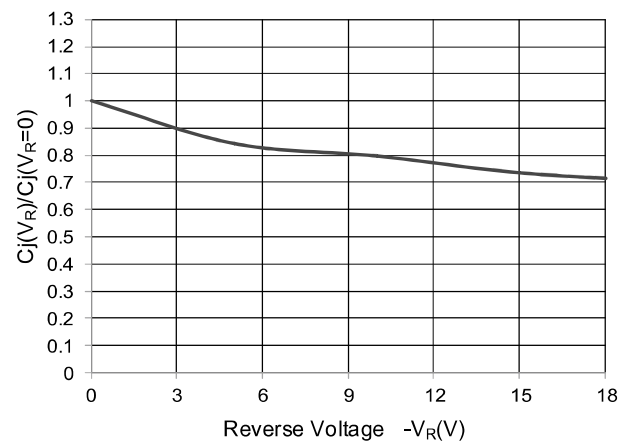


Figure 5: TLP Positive I-V Curve

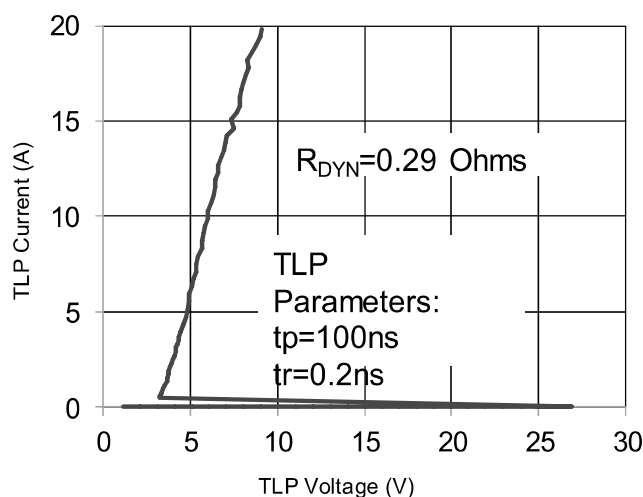
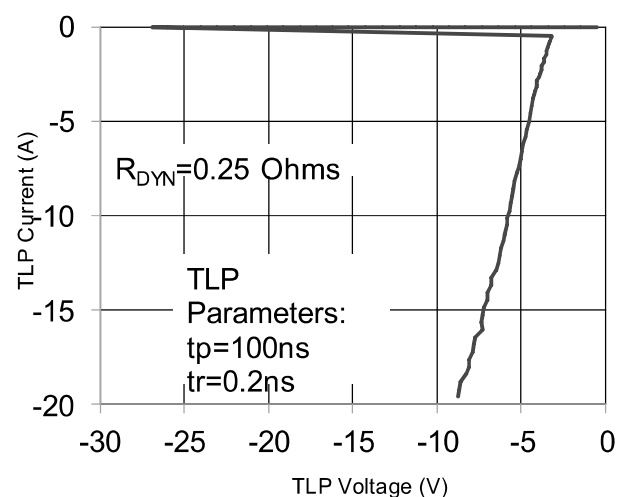
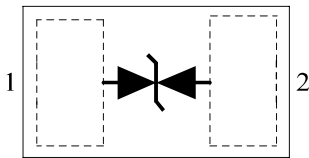


Figure 6: TLP Negative I-V Curve

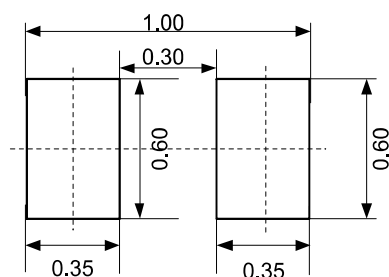


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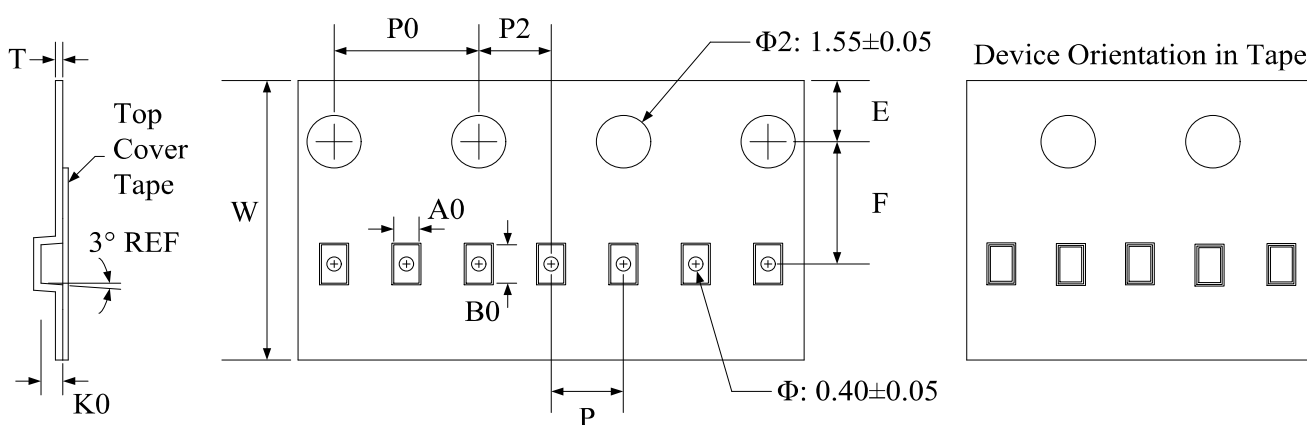
Pinning & Marking information

Marking Code	Symbol
 WF=Specific Device Code X=Month Code	

Suggested solder pad layout



Packing information



Symbol	W	A0	B0	K0	E	F	P	P0	P2	T
Dimensions (mm)	8.00±0.1	0.7±0.05	1.15±0.05	0.55±0.05	1.75±0.1	3.5±0.05	2.0±0.1	4.0±0.1	2.0±0.05	0.2±0.05

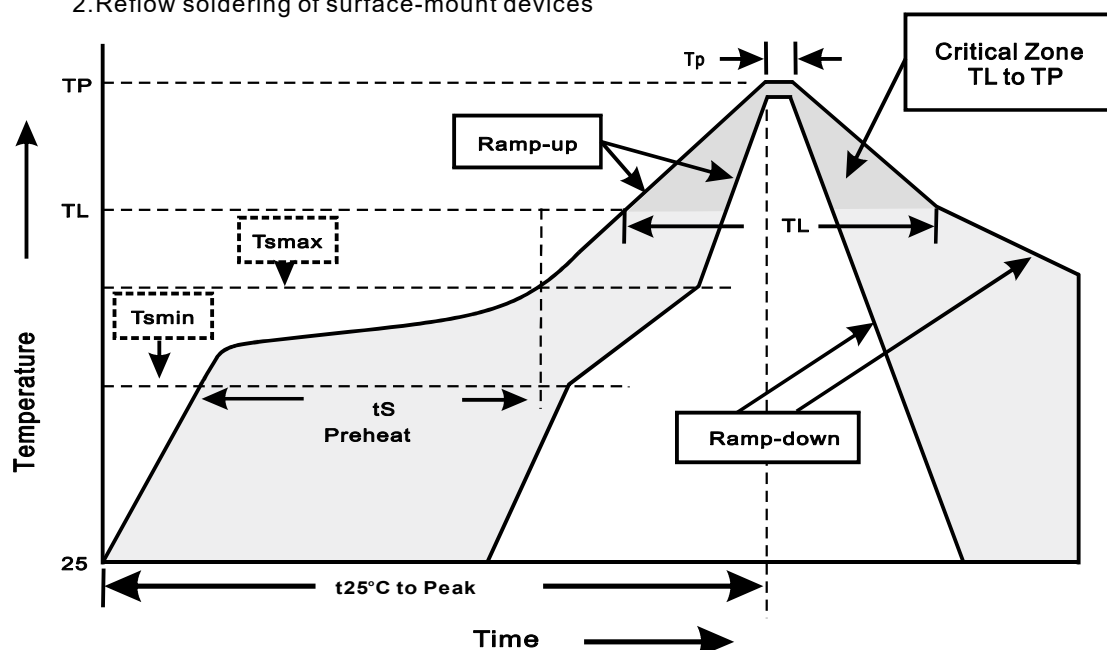
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Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (m/m)	BOX (pcs)	INNER BOX (m/m)	REEL DIA, (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
T1006P2	7"	10,000	4.0	100,000	183*123*183	178	382*257*387	800,000	15.0

Suggested thermal profiles for soldering processes

- 1.Storage environment: Temperature=5°C~40°C Humidity=55%±25%
- 2.Reflow soldering of surface-mount devices



3.Reflow soldering

Profile Feature	Soldering Condition
Average ramp-up rate(T _L to T _P)	<3°C/sec
Preheat -Temperature Min(T _{smmin}) -Temperature Max(T _{smmax}) -Time(min to max)(t _s)	150°C 200°C 60~120sec
T _{smmax} to T _L -Ramp-upRate	<3°C/sec
Time maintained above: -Temperature(T _L) -Time(t _L)	217°C 60~260sec
Peak Temperature(T _P)	255°C-0/+5°C
Time within 5°C of actual Peak Temperature(t _P)	10~30sec
Ramp-down Rate	<6°C/sec
Time 25°C to Peak Temperature	<6minutes